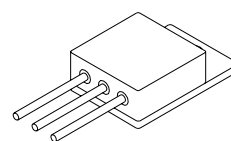
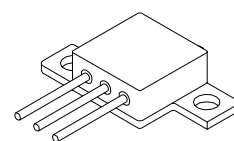


SOLID STATE DEVICES, INC.14005 Stage Road * Santa Fe Springs, Ca 90670
Phone: (562) 404-4474 * Fax: (562) 404-1773**Designer's Data Sheet****FEATURES:**

- Hyper Fast Recovery: 30nsec Maximum
- High Surge Rating
- Low Reverse Leakage Current
- Low Junction Capacitance
- Hermetically Sealed Package
- Gold Eutectic Die Attach Available
- Ultrasonic Aluminum Wire Bonds
- Common Anode and Doubler Versions Available
- TX, TXV and Space Level Screening Available

40AMPS
600 VOLTS
30 nsec
HYPER FAST
CENTERTAP RECTIFIER

TO-254**TO-254Z**

Maximum Ratings	SYMBOL	VALUE	UNITS
Peak Repetitive Reverse and DC Blocking Voltage SDR656CTM & Z	V_{RRM} V_{RWM} V_R	600	Volts
Average Rectified Forward Current. (Resistive load, 60Hz, Sine Wave, $T_A = 25^\circ\text{C}$) <u>1/</u>	I_o	40	Amps
Peak Surge Current (8.3 ms Pulse, Half Sine Wave, $T_A = 25^\circ\text{C}$) <u>2/</u>	I_{FSM}	200	Amps
Operating and Storage Temperature	T_{OP} & T_{STG}	-65 TO +175	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Case, each individual diode Junction to Case, <u>1/</u>	$R_{\theta JC}$	2.0 1.0	$^\circ\text{C/W}$

1/ Both legs tied together2/ Per leg

NOTE: All specifications are subject to change without notification.
 SCD's for these devices should be reviewed by SSDI prior to release.

DATA SHEET #: RC0028A

SDR656CTM & Z

PRELIMINARY



SOLID STATE DEVICES, INC.

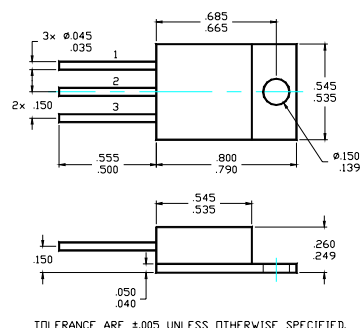
14005 Stage Road * Santa Fe Springs, Ca 90670

Phone: (562) 404-4474 * Fax: (562) 404-1773

Electrical Characteristics (per leg)	SYMBOL	VALUE	UNITS
Instantaneous Forward Voltage Drop ($I_F = 10A$ $T_A = 25^\circ C$, 300 μ sec pulse) ($I_F = 20A$ $T_A = 25^\circ C$, 300 μ sec pulse)	V_F	1.35 1.55	V_{DC} V_{DC}
Instantaneous Forward Voltage Drop ($I_F = 10A$ $T_A = 100^\circ C$, 300 μ sec pulse) ($I_F = 10A$ $T_A = -55^\circ C$, 300 μ sec pulse)	V_F	1.25 1.45	V_{DC} V_{DC}
Reverse Leakage Current (Rated V_R , $T_A = 25^\circ C$, 300 μ s pulse minimum)	I_R	50	μA
Reverse Leakage Current (Rated V_R , $T_A = 100^\circ C$, 300 μ s pulse minimum)	I_R	5	mA
Junction Capacitance ($V_R = 10V_{DC}$, $T_A = 25^\circ C$, $f = 1MHz$)	C_J	50	pf
Reverse Recovery Time ($T_A = 25^\circ C$, $I_F = 0.5A$, $I_R = 1.0A$, $I_{RR} = 0.25A$)	T_{RR}	30	nsec

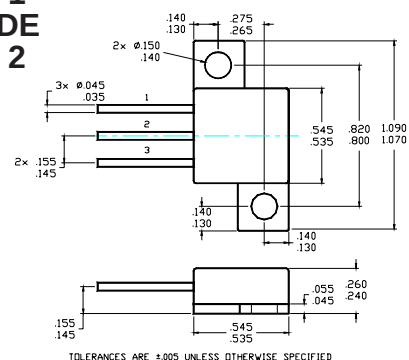
CASE OUTLINE: TO-254

PIN 1: ANODE 1
PIN 2: CATHODE
PIN 3: ANODE 2



CASE OUTLINE: TO-254Z

PIN 1: ANODE 1
PIN 2: CATHODE
PIN 3: ANODE 2



TYPICAL OPERATING CURVES

$T_A = 25^\circ C$ Unless otherwise specified

